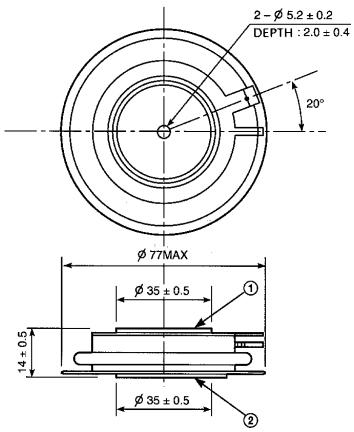
TOSHIBA FAST RECOVERY DIODE SILICON DIFFUSED TYPE

500YKH22

HIGH SPEED RECTIFIER APPLICATIONS

Unit in mm

- Repetitive Peak Reverse Voltage : V_{RRM} = 2700V
- Average Forward Current : $I_{F(AV)}$ = 500A
- Reverse Recovery Time : t_{rr} = 5μs (MAX.) (T_j = 25°C)



1. CATHODE
2. ANODE

JEDEC	—
EIAJ	—
TOSHIBA	3-77A1A

Weight : 220g

MAXIMUM RATINGS

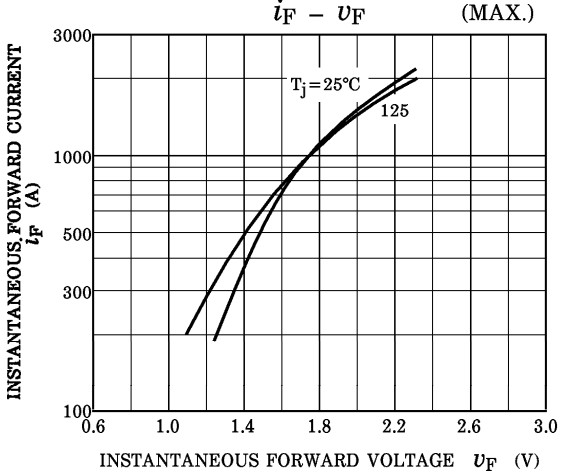
CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive Peak Reverse Voltage	V_{RRM}	2700	V
Non-Repetitive Peak Reverse Voltage (Non-Repetitive ≦ 5ms, T_j = 0~125°C)	V_{RSM}	2800	V
Average Forward Current	$I_{F(AV)}$	500	A
Peak One Cycle Surge Forward Current	I_{FSM}	10000 (50Hz)	A
		11000 (60Hz)	
Junction Temperature Range	T_j	−40~125	°C
Storage Temperature Range	T_{stg}	−40~125	°C
Mounting Force	—	14.7 ± 1.5	kN

ELECTRICAL CHARACTERISTICS

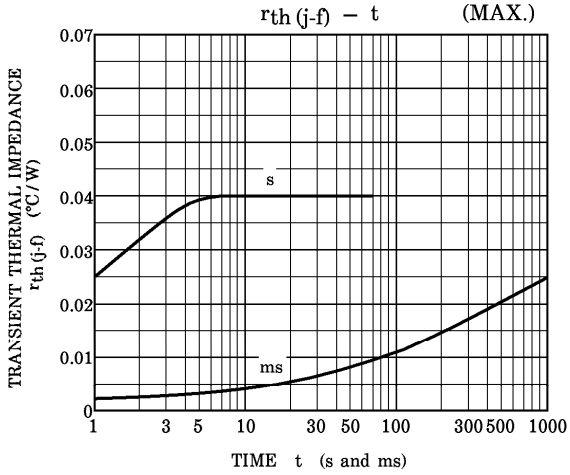
CHARACTERISTIC	SYMBOL	TEST CONDITION		MIN.	MAX.	UNIT
Repetitive Peak Reverse Current	I_{RRM}	V_{RRM} = 2500V, T_j = 125°C		—	100	mA
Peak Forward Voltage	V_{FM}	I_{FM} = 1500A, T_j = 25°C		—	2.0	V
Reverse Recovery Time	t_{rr}	I_F = 500A, di_F/dt = 100A/μs	T_j = 25°C	—	5.0	μs
			T_j = 125°C	—	6.0	
Thermal Resistance (Junction to Fin)	$R_{th(j-f)}$	DC		—	0.04	°C/W

961001EAA2

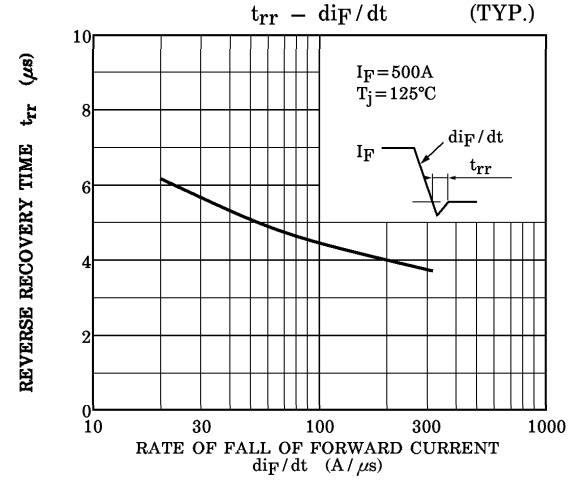
$i_F - v_F$ (MAX.)



$r_{th\,(j\text{-}f)} - t$ (MAX.)



$t_{rr} - di_F/dt$ (TYP.)



I_{rr}, $Q_{rr} - di_F/dt$ (TYP.)